NSN 5961-01-464-1751

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-1751 **Inclosure Material:** Glass **Overall Length:** 4.2 millimeters **Terminal Length:** 26.0 millimeters **Overall Diameter:** 2.0 millimeters **End Application:** 6625-01-425-2551 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Terminal Circle Diameter:** 2.000 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, peak and 70.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 450.00 milliamperes source cutoff current absolute and 1.00 amperes forward current, average preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 5.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No